

UNITED STATES PATENT AND TRADEMARK OFFICE
CERTIFICATE OF CORRECTION

PATENT NO. : 6,971,432 B2
APPLICATION NO. : 10/639460
DATED : December 6, 2005
INVENTOR(S) : Kazutaka Yanagita et al.

Page 1 of 1

It is certified that error appears in the above-identified patent and that said Letters Patent is hereby corrected as shown below:

Title Page

In Item (56), Title Page 2, Line 9, OTHER PUBLICATIONS, change:

“Oxidized Porous Silicon and It’s Application”, K. Nagano et al., *The Transactions of the Institute of Electronics and Communication Engineers*, The Institute of Electronics, Information and Communication” to

--“Oxidized Porous Silicon and It’s Application”, K. Nagano et al., *The Transactions of the Institute of Electronics and Communication Engineers*, The Institute of Electronics, Information and Communication”.--

Signed and Sealed this

Twentieth Day of November, 2007



JON W. DUDAS
Director of the United States Patent and Trademark Office